NSN 5962-01-016-7266

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-016-7266

Body Length:

Between 0.365 inches and 0.385 inches

Body Width:

Between 0.240 inches and 0.260 inches

Body Height:

Between 0.035 inches and 0.070 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

Features Provided:

Hermetically sealed and high speed and programmable and programmed and w/buffered output and w/decoded output and w/enable and

3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

94117-310403 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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